

Qualification Report For PCN# 20110901001 Die Conversion for Selected LVC LL Devices in the DBV and DCK Packages

Date: 12/15/2011

Dear Customer:

Texas Instruments is pleased to announce the completion of qualification testing for the product change described in PCN# 20110901001. The details of the qualification results are included in the following pages and are being forwarded to you in response to your inquiry about this PCN.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (<u>PCN_ww_admin_team@list.ti.com</u>).

Sincerely,

PCN Team SC Business Services Phone: +1(214) 480-6037 Fax: +1(214) 480-6659



12500 TI Boulevard, MS 8640, Dallas, Texas 75243

Qualification Report For PCN# 20110901001 Die Conversion for Selected LVC LL Devices in the DBV and DCK Packages

Qualification Data: DCK Devices (Approved 8/04/2011)						
This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.						
	Qualification Device Cor	nstruction Deta	ils:			
Qualification Vehicle #1: SN74LVC1G00DCKR						
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000/1 iN500	Wafer Size Dia.	200mm			
Qualification:	lan 🛛 Test Results					
Reliability Test	Conditions		Sample Size(PASS/FAIL)			
Manufacturability-TQ	Assembly (per mfg. Site s	pecification)	PASS			
X-Ray	Approved by A-T Site		PASS			
Notes: Qualific	cation tests "pass" on zero fai	ls for each test				
	Qualification Vehicle #2:	SN74LVC1G02	DCKR			
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm			
Qualification:	lan 🛛 Test Results					
Reliability Test	Conditions		Sample Size(PASS/FAIL)			
Electrical Char -LV	Approved by Product Engi	neer	PASS			
Manufacturability-TQ	Approved by A-T Site		PASS			
Notes: Qualific	cation tests "pass" on zero fai	ls for each test				
	Qualification Vehicle #3:	SN74LVC1G04	DCKR			
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm			
Qualification:	lan 🛛 Test Results					
Reliability Test	Conditions		Sample Size (PASS/FAIL)			
Manufacturability-TQ	Approved by A-T Site		PASS			
Notes: Qualific	cation tests "pass" on zero fai	ls for each test				
	Qualification Vehicle #4:	SN74LVC1G06	DCKR			
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792			
Protective Die Coating: Ti300/TiN1700/AlCu0.5=6000 /TiN500 Wafer Size Dia			200mm			
Qualification:	lan 🛛 Test Results					
Reliability Test	Conditions		Sample Size (PASS/FAIL)			
Electrical Char - LV	Approved by Product Engi	neer	PASS			
Manufacturability-TQ	Approved by A-T Site		PASS			
Notes: Qualification tests "pass" on zero fails for each test						

	Qualification Vehicle #5: SN74LVC1G07DCKR					
Wafer Fab Site:	FFAB	Wafer Process:	50b ⁻	10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm			
Qualification:	Plan 🛛 Test Results					
Reliability Test	Conditions			Sample Size (PASS/FAIL)		
Electrical Char - LV	Approved by Product Eng	ineer		PASS		
Manufacturability-TQ	Approved by A-T Site			PASS		
Notes: Qualifie	cation tests "pass" on zero fa	ils for each test				
	Qualification Vehicle #6:	SN74LVC1G08D	CKR			
Wafer Fab Site:	FFAB	Wafer Process:	50b´	10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200m	ım		
Qualification:	Plan 🛛 Test Results					
Reliability Test	Conditions		Sample Size (PASS/FAIL)			
Electrical Char - LV	Approved by Product Eng	ineer	PASS			
Manufacturability-TQ	Approved by A-T Site		PASS			
Notes: Qualific	cation tests "pass" on zero fa	ils for each test				
Qualification Vehicle #7: SN74LVC1G14DCKR						
Wafer Fab Site:	FFAB	Wafer Process:	er Process: 50b10.13_BOPO2 / P9792			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200m	nm		
Qualification:	Plan 🛛 Test Results					
Reliability Test	Conditions			Sample Size (PASS/FAIL)		
Electrical Char - LV	Approved by Product Eng	ineer		PASS		
Manufacturability-TQ	Approved by A-T Site			PASS		
Notes: Qualific	cation tests "pass" on zero fa	ils for each test				
	Qualification Vehicle #8:	SN74LVC1G17D	CKR			
Wafer Fab Site:	FFAB	Wafer Process:	50b´	10.13_BOPO2 / P9792		
Protective Die Coating: Ti300/TiN1700/AICu0.5=6000 Wafer Size Dia. 200r			200m	ım		
Qualification:	Plan 🛛 Test Results					
Reliability Test Conditions			Sample Size (PASS/FAIL)			
Electrical Char - LV	Approved by Product Eng	ineer		PASS		
Manufacturability-TQ	Approved by A-T Site			PASS		
Notes: Qualification tests "pass" on zero fails for each test						

	Qualification Vehicle #9: SN74LVC1G32DCKR					
Wafer Fab Site:	FFAB	Wafer Process:	50b ⁻	10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm			
Qualification:	Plan 🛛 Test Results					
Reliability Test	Conditions			Sample Size (PASS/FAIL)		
Electrical Char - LV	Approved by Product Eng	ineer		PASS		
Manufacturability-TQ	Approved by A-T Site			PASS		
Notes: Qualific	cation tests "pass" on zero fa	ils for each test				
	Qualification Vehicle #10:	SN74LVC1G34E	DCKR			
Wafer Fab Site:	FFAB	Wafer Process:	50b ⁻	10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	nm		
Qualification:	Plan 🛛 Test Results					
Reliability Test	Conditions		Sample Size (PASS/FAIL)			
Electrical Char - LV	Approved by Product Eng	ineer	PASS			
Manufacturability-TQ	Anufacturability-TQ Approved by A-T Site PAS			PASS		
Notes: Qualific	cation tests "pass" on zero fa	ils for each test				
Qualification Vehicle #11: SN74LVC1G38DCKR						
Wafer Fab Site:	FFAB	Wafer Process:	50b ⁻	10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	nm		
Qualification:	Plan 🛛 Test Results					
Reliability Test	Conditions			Sample Size (PASS/FAIL)		
Electrical Char - LV	Approved by Product Eng	ineer		PASS		
Manufacturability-TQ	Approved by A-T Site			PASS		
Notes: Qualific	cation tests "pass" on zero fa	ils for each test				
C	Qualification Vehicle #12:	SN74LVC1GU04	DCKF	2		
Wafer Fab Site:	FFAB	Wafer Process:	50b ⁻	10.13_BOPO2 / P9792		
Protective Die Coating: Ti300/TiN1700/AlCu0.5=6000 Wafer Size Dia. 200mr			nm			
Qualification: Plan I Test Results						
Reliability Test Conditions				Sample Size (PASS/FAIL)		
Electrical Char - LV Approved by Product Engineer			PASS			
Manufacturability-TQ	Approved by A-T Site			PASS		
Notes: Qualific	cation tests "pass" on zero fa	ils for each test				

Qualification Data: DBV Devices (Approved 8/22/2011)

This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.

Qualification Device Construction Details:					
	Qualification Vehicle #1:	SN74LVC1G00DE	3VR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification:	Plan 🛛 Test Results				
Reliability Test Conditions Sample S (PASS/F/			Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Eng	ineer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS	
ESD CDM	1500V			3/0	
X-Ray	Approved by A-T Site; Bo	ttom side Only		5/0	
Notes: Qualification tests "pass" on zero fails for each test					
Qualification Vehicle #2: SN74LVC1G02DBVR					
Wafer Fab Site:	FFAB	Wafer Process:	50b10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	e Dia. 200mm		
Qualification:	Plan 🛛 Test Results	•			
Reliability Test Conditions			Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Eng	ineer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS	
ESD CDM	1500V	-	3/0		
Notes: Qualific	cation tests "pass" on zero fai	Is for each test			
	Qualification Vehicle #3:	SN74LVC1G04DE	BVR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia. 200mm		าฑ	
Qualification: Plan I Test Results					
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char	Electrical Char Approved by Product Engineer			PASS	
Manufacturability-TQ Assembly (per mfg. Site specification)			PASS		
ESD CDM	1500V		3/0		
Notes: Qualification tests "pass" on zero fails for each test					

Qualification Vehicle #4: SN74LVC1G06DBVR					
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	200mm	
Qualification:	an 🛛 Test Results				
Reliability TestConditionsSample Size(PASS/FAI)			Sample Size (PASS/FAIL)		
Electrical Char -LV	Approved by Product Eng	ineer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS	
ESD CDM	1500V			3/0	
Notes: Qualification	ation tests "pass" on zero fai	Is for each test			
	Qualification Vehicle #5:	SN74LVC1G07DE	<u>BVR</u>		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	nm	
Qualification:	an 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char -I V	Approved by Product Engl	ineer		PASS	
Manufacturability-TQ	Anufacturability-TO Assembly (per mfg_Site specification)			PASS	
ESD CDM	1500V			3/0	
Notes: Qualifica	ation tests "pass" on zero fai	Is for each test			
	Qualification Vehicle #6:	SN74LVC1G08DE	3VR		
Wafer Fab Site: FFAB Wafer Process: 50b		50b1	0.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	nm	
Qualification:	an 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char -LV	Approved by Product Engl	ineer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS	
ESD CDM	1500V	•		3/0	
Notes: Qualific	ation tests "pass" on zero fai	Is for each test			
	Qualification Vehicle #7:	SN74LVC1G14DE	BVR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792	
Protective Die Coating: Ti300/TiN1700/AlCu0.5=6000 Wafer Size Dia. 200		200n	nm		
Qualification: Plan X Test Results					
Reliability Test Conditions			Sample Size (PASS/FAIL)		
Electrical Char -I V Approved by Product Engineer				PASS	
Manufacturability-TO Assembly (ner mfg. Site specification)			PASS		
ESD CDM	1500V			3/0	
Notes: Qualifica	Notes: Qualification tests "pass" on zero fails for each test				

	Qualification Vehicle #8: SN74LVC1G17DBVR					
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	200mm		
Qualification:	lan 🛛 Test Results					
Reliability Test	Conditions			Sample Size (PASS/FAIL)		
Electrical Char -LV	Approved by Product Eng	ineer		PASS		
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS		
ESD CDM	1500V			3/0		
Notes: Qualific	ation tests "pass" on zero fai	Is for each test				
	Qualification Vehicle #9:	SN74LVC1G32DE	<u>BVR</u>			
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AICu0.5=6000 /TiN500	Wafer Size Dia.	200n	nm		
Qualification:	Ian 🛛 Test Results					
Reliability Test	Conditions			Sample Size (PASS/FAIL)		
Electrical Char -LV	Electrical Char -LV Approved by Product Engineer			PASS		
Manufacturability-TQ	urability-TQ Assembly (per mfg. Site specification) PASS			PASS		
ESD CDM 1500V				3/0		
Notes: Qualific	ation tests "pass" on zero fai	Is for each test				
	Qualification Vehicle #10	SN74LVC1G34D	BVR			
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200n	nm		
Qualification:	Ian 🛛 Test Results	·				
Reliability Test	Conditions			Sample Size (PASS/FAIL)		
Electrical Char -LV	Approved by Product Eng	ineer		PASS		
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS		
ESD CDM	1500V			3/0		
Notes: Qualific	ation tests "pass" on zero fai	Is for each test				
	Qualification Vehicle #11	: SN74LVC1G38D	BVR			
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792		
Protective Die Coating: Ti300/TiN1700/AlCu0.5=6000 Wafer Size Dia. 200mm		nm				
Qualification: P	lan 🛛 Test Results					
Reliability Test Conditions			Sample Size (PASS/FAIL)			
Electrical Char -LV	Approved by Product Ena	ineer		PASS		
Manufacturability-TQ Assembly (per mfg. Site specification)			PASS			
ESD CDM	1500V	. ,		3/0		
Notes: Qualific	Notes: Qualification tests "pass" on zero fails for each test					

Qualification Vehicle #12: SN74LVC1GU04DBVR						
Wafer Fab Site:	FFAB	Wafer Process:	50b1	50b10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm			
Qualification: 🗌 Plan 🛛 Test Results						
Reliability Test	Conditions			Sample Size (PASS/FAIL)		
Electrical Char -LV	Approved by Product Eng	ineer		PASS		
Manufacturability-TQ Assembly (per mfg. Site specification)			PASS			
ESD CDM	SD CDM 1500V			3/0		
Notes: Qualification tests "pass" on zero fails for each test						

Reference Qualification: LVC Little Logic Devices in 6 Pin DSF 1G00/1G02/1G08/1G32/1G38 – HNT

Qualifica	Qualification Data: DSF Devices (Approved 3/30/2011)				
This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.					
	Qualification Device Cor	nstruction Detail	s:		
	Qualification Vehicle #1:	SN74LVC1G00D	SFR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification: Plan I Test Results					
Reliability Test Conditions			Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Engi	ineer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS	
ESD CDM	1500V			3/0	
X-Ray	Approved by A-T Site; Bo	ttomside Only		5/0	
ESD MM	250V			3/0	
ESD HBM	3500V			3/0	
Latch Up	JESD 78, Class II			6/0	
Steady State Life Test 150C, 300 Hrs		77/0			
Manufacturability (assy)				Pass	
Notes: Qualific	ation tests "pass" on zero fai	Notes: Qualification tests "pass" on zero fails for each test			

Qualification Vehicle #2: SN74LVC1G02DSFR					
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char	Approved by Product Eng	ineer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS	
ESD CDM	1500V			3/0	
Latch-Up	JESD 78, Class II			6/0	
ESD MM	200V			3/0	
ESD HBM	4000V			3/0	
Notes: Qualifie	cation tests "pass" on zero fa	ils for each test			
	Qualification Vehicle #3	SN74LVC1G08D	SFR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test Conditions Sam			Sample Size (PASS/FAIL)		
Electrical Char	Approved by Product Eng	ineer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS	
ESD CDM	1500V	•		3/0	
ESD MM	200V			3/0	
Latch Up	JESD 78, Class II			6/0	
ESD HBM	4000V			3/0	
Notes: Qualific	cation tests "pass" on zero fa	ils for each test			
	Qualification Vehicle #4	: SN74LVC1G32D	SFR		
Wafer Fab Site:	FFAB	Wafer Process:	50b1	10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200r	nm	
Qualification:	Plan 🛛 Test Results				
Reliability Test	Conditions			Sample Size (PASS/FAIL)	
Electrical Char Approved by Product Engineer			PASS		
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS	
ESD CDM 1500V		3/0			
ESD MM	SD MM 250V		3/0		
ESD HBM	SD HBM 3500V			3/0	
Latch Up JESD 78, Class II			6/0		
Notes: Qualific	cation tests "pass" on zero fa	ils for each test			

Qualification Vehicle #5: SN74LVC1G38DSFR					
Wafer Fab Site:	FFAB	Wafer Process:	eess: 50b10.13_BOPO2 / P9792		
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm		
Qualification: Plan Test Results					
Reliability Test	Conditions	Conditions		Sample Size (PASS/FAIL)	
Electrical Char	Approved by Product Engi	neer		PASS	
Manufacturability-TQ	Assembly (per mfg. Site s	pecification)		PASS	
ESD CDM	1500V			3/0	
Latch-Up JESD 78, Class II			6/0		
ESD MM	SD MM 200V			3/0	
ESD HBM	SD HBM 4000V		3/0		
Notes: Qualification tests "pass" on zero fails for each test					

Reference Qualification: LVC Little Logic Devices in 6 Pin DSF 1G04/1G06/1G07/1G14/1G17/1G34/1GU04 – HNT

Qualification Data: DSF Devices (Approved 6/27/2011)				
This qualification has b	peen specifically developed for	r the validation of	this o	hange. The
qualification data valid	ates that the proposed chang	e meets the applie	cable	released technical
specifications.				
	Qualification Device Cor	nstruction Detail	s:	
	Qualification Vehicle #1:	SN74LVC1G04D	SFR	
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm	
Qualification: 🗌 Plan 🛛 Test Results				
Reliability Test	Conditions	Conditions		Sample Size
Electrical Char	Approved by Product Engi	ineer		PASS
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS
ESD CDM	1500V	· · · · ·		3/0
X-Ray	Approved by A-T Site; Bo	ttomside Only		5/0
ESD MM	250V			3/0
ESD HBM 5000V		3/0		
Latch Up JESD 78, Class II		6/0		
Steady State Life Test 150C, 300 Hrs			77/0	
Notes: Qualifie	cation tests "pass" on zero fai	Is for each test		

	Qualification Vehicle #2: SN74LVC1G06DSFR						
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm				
Qualification:	Plan 🛛 Test Results						
Reliability Test Conditions Sample Size (PASS/FAIL)				Sample Size (PASS/FAIL)			
Electrical Char	Approved by Product Eng	ineer		PASS			
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS			
ESD CDM	1500V			3/0			
Latch-Up	JESD 78, Class II			6/0			
ESD MM	200V			3/0			
ESD HBM	3500V			3/0			
Notes: Qualifie	cation tests "pass" on zero fai	ils for each test					
	Qualification Vehicle #3:	SN74LVC1G07DS	SFR				
Wafer Fab Site:	FFAB	Wafer Process:	50b1	0.13_BOPO2 / P9792			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200mm				
Qualification: 🗌 Plan 🛛 Test Results							
Reliability Test Conditions Sample S (PASS/FA)			Sample Size (PASS/FAIL)				
Electrical Char	Approved by Product Eng	ineer		PASS			
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS			
ESD CDM	1500V	•		3/0			
ESD MM	250V			3/0			
Latch Up	JESD 78, Class II			6/0			
ESD HBM	4000V	4000V					
Notes: Qualifie	cation tests "pass" on zero fai	ils for each test					
	Qualification Vehicle #4	SN74LVC1G14D	SFR				
Wafer Fab Site:	FFAB	Wafer Process:	50b1	10.13_BOPO2 / P9792			
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500	Wafer Size Dia.	200r	nm			
Qualification:	Plan 🛛 Test Results						
Reliability Test	Conditions			Sample Size (PASS/FAIL)			
Electrical Char	Approved by Product Eng	ineer		PASS			
Manufacturability-TQ	Assembly (per mfg. Site s	specification)		PASS			
ESD CDM 1500V		3/0					
ESD MM	M 250V		3/0				
ESD HBM	ESD HBM 4000V			3/0			
Latch Up JESD 78, Class II			6/0				
Notes: Qualification tests "pass" on zero fails for each test							

Qualification Vehicle #5: SN74LVC1G17DSFR					
Wafer Fab Site:	FFAB		Wafer Process:	50b10.13_BOPO2 / P9792	
Protective Die Coating:	Ti300/TiN1700/AlCu0.5=6000 /TiN500		Wafer Size Dia.	200mm	
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test		Conditions			Sample Size (PASS/FAIL)
Electrical Char		Approved by Product Engineer			PASS
Manufacturability-TQ		Assembly (per mfg. Site specification)			PASS
ESD CDM		1500V			3/0
Latch-Up		JESD 78, Class II			6/0
ESD MM		250V			3/0
ESD HBM		2000V		3/0	
Notes: Qualification tests "pass" on zero fails for each test					
Qualification Vehicle #6: SN74LVC1G34DSFR					
Wafer Fab Site:	F	FAB	Wafer Process:	50b10.13_BOPO2 / P9792	
Protective Die Coating:	g: Ti300/TiN1700/AlCu0.5=6000 /TiN500		Wafer Size Dia.	200mm	
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test		Conditions			Sample Size (PASS/FAIL)
Electrical Char		Approved by Product Engineer			PASS
Manufacturability-TQ		Assembly (per mfg. Site specification)			PASS
ESD CDM		1500V			3/0
ESD MM		250V			3/0
ESD HBM		4000V			3/0
Latch Up		JESD 78, Class II			6/0
Notes: Qualification tests "pass" on zero fails for each test					
Qualification Vehicle #7: SN74LVC1GU04DSFR					
Wafer Fab Site:	F	FAB	Wafer Process:	50b10.13_BOPO2 / P9792	
Protective Die Coating:	Ti /T	300/TiN1700/AlCu0.5=6000 ïIN500	Wafer Size Dia.	200mm	
Qualification: 🗌 Plan 🛛 Test Results					
Reliability Test		Conditions			Sample Size (PASS/FAIL)
Electrical Char		Approved by Product Engineer			PASS
Manufacturability-TQ		Assembly (per mfg. Site specification)			PASS
ESD CDM		1500V			3/0
Latch-Up		JESD 78, Class II			6/0
ESD MM		250V			3/0
ESD HBM		2000V			3/0
Notes: Qualification tests "pass" on zero fails for each test					

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Reliability data shows characteristic failure mechanisms of the specific environmental stress as documented in the industry standards for each stress condition.

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